

High Voltage Fast-Switching NPN Power Transistor

FJPF13007

- High Voltage Capability
- High Switching Speed
- Suitable for Electronic Ballast and Switching Mode Power Supply
- This is a Pb–Free Device

MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

| Symbol | Parameter | Value | Unit |
|------------------|---|---------|------|
| V_{CBO} | Collector-Base Voltage | 700 | V |
| V _{CEO} | Collector–Emitter Voltage | 400 | V |
| V _{EBO} | Emitter-Base Voltage | 9 | V |
| I _C | Collector Current (DC) | 8 | Α |
| I _{CP} | Collector Current (Pulse) | 16 | Α |
| I _B | Base Current | 4 | Α |
| P _C | Collector Dissipation (T _C = 25°C) | 40 | W |
| T_J | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | -65~150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

hFE CLASSIFICATION

| Classification | H1 | H2 |
|------------------|-------|-------|
| h _{FE1} | 15~28 | 26~39 |

- 1. Base
- Collector
 Emitter
- TO-220 Fullpack, 3-Lead CASE 221AT

MARKING DIAGRAM

J13007 -x AYWWZZ

J13007- = Specific Device Code

 $\begin{array}{lll} x & = h_{FE} \mbox{ Grade} \\ A & = \mbox{Site Code} \\ Y & = \mbox{ Year} \\ WW & = \mbox{ Work Week} \\ ZZ & = \mbox{ Assembly Lot Code} \\ \end{array}$

ORDERING INFORMATION

| Device | Package | Shipping |
|---------------|--------------------|-------------------|
| FJPF13007H2TU | TO-220 Fullpack | 1000 Units / Tube |

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------------------------|--------------------------------------|--|-------------|-------------|-------------------|-------------|
| BV _{CEO} | Collector-Emitter Breakdown Voltage | I _C = 10 mA, I _B = 0 | 400 | _ | _ | V |
| I _{EBO} | Emitter Cut-off Current | V _{EB} = 9 V, I _C = 0 | - | - | 1 | μΑ |
| h _{FE1} h _{FE2} | DC Current Gain | V _{CE} = 5 V, I _C = 2 A V _{CE} = 5 V, I _C = 5 A | 8 5 | | 60 30 | |
| V _{CE(sat)} | Collector–Emitter Saturation Voltage | I _C = 2 A, I _B = 0.4 A I _C = 5 A, I _B = 1 A I _C = 8 A, I _B = 2 A | - - - | - - - | 1.0 2.0 3.0 | V V V |
| V _{BE(sat)} | Base–Emitter Saturation Voltage | I _C = 2 A, I _B = 0.4 A I _C = 5 A, I _B = 1 A | _ | | 1.2 1.6 | V |
| f _T | Current Gain Bandwidth Product | V _{CE} = 10 V, I _C = 0.5 A | 4 | _ | _ | MHz |
| C _{ob} | Output Capacitance | V _{CB} = 10 V, f = 0.1 MHz | - | 110 | - | pF |
| t _{ON} | Turn On Time | $V_{CC} = 125 \text{ V}, I_C = 5 \text{ A}, I_{B1} = -I_{B2} = 1 \text{ A},$ | _ | _ | 1.6 | μs |
| t _{STG} | Storage Time | $R_L = 25 \Omega$ | _ | _ | 3.0 | μS |
| t _F | Fall Time | | _ | _ | 0.7 | μS |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. *Pulse Test: $PW \le 300 \ \mu s$, Duty Cycle $\le 2\%$

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TYPICAL CHARACTERISTICS

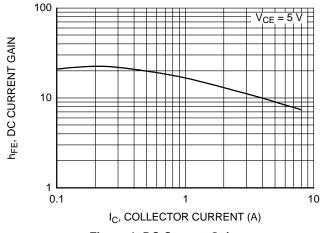


Figure 1. DC Current Gain

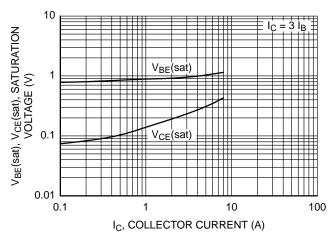


Figure 2. Saturation Voltage

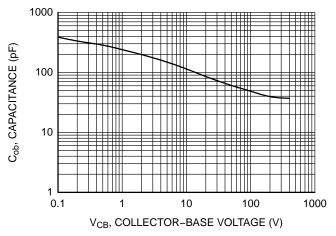


Figure 3. Collector Output Capacitance

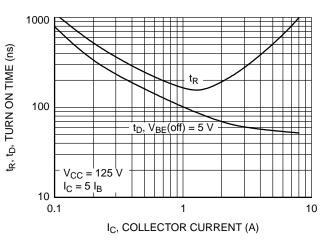


Figure 4. Turn On Time

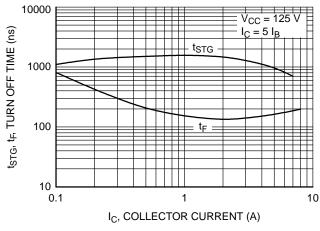


Figure 5. Turn Off Time

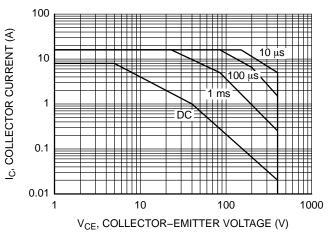


Figure 6. Forward Biased Safe Operating Area

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TYPICAL CHARACTERISTICS (CONTINUED)

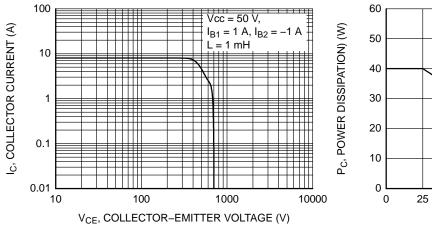


Figure 7. Reverse Biased Safe Operating Area

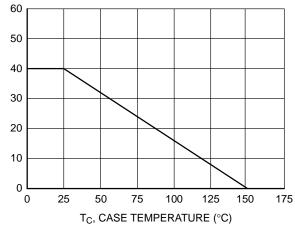
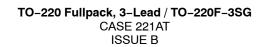
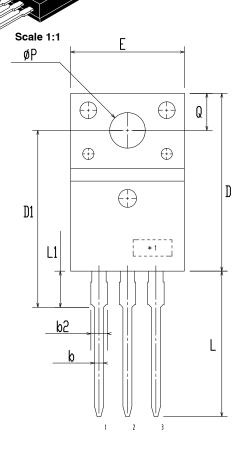


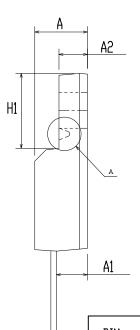
Figure 8. Power Derating

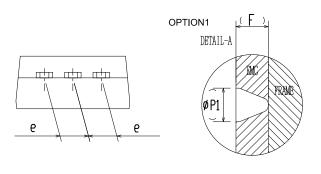




DATE 19 JAN 2021







| DIM | HILLIHITEKS | | |
|-------|-------------|-------|-------|
| ויונע | MIN | NDM | MAX |
| Α | 4.50 | 4.70 | 4.90 |
| A1 | 2.56 | 2.76 | 2.96 |
| A2 | 2.34 | 2.54 | 2.74 |
| b | 0.70 | 0.80 | 0.90 |
| b2 | ~ | 2 | 1.47 |
| С | 0.45 | 0.50 | 0.60 |
| D | 15.67 | 15.87 | 16.07 |
| D1 | 15.60 | 15.80 | 16.00 |
| E | 9.96 | 10.16 | 10.36 |
| е | 2.34 | 2.54 | 2.74 |
| F | ~ | 0.84 | ~ |
| H1 | 6.48 | 6.68 | 6.88 |
| L | 12.78 | 12.98 | 13.18 |
| L1 | 3.03 | 3.23 | 3.43 |
| øΡ | 2.98 | 3.18 | 3.38 |
| ø P1 | ~ | 1.00 | ~ |
| Q | 3.20 | 3.30 | 3.40 |
| | | | |

MILL IMITERS

NOTES:

- A. DIMENSION AND TOLERANCE AS ASME Y14.5-2009
- B. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUCSIONS.

C

C. OPTION 1 - WITH SUPPORT PIN HOLE OPTION 2 - NO SUPPORT PIN HOLE

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|------------------|---|--|-------------|--|
| DESCRIPTION: | DN: TO-220 FULLPACK, 3-LEAD / TO-220F-3SG | | PAGE 1 OF 1 | |

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